

STG3693

Low voltage high bandwidth Quad SPDT switch

Features

- Ultra low power dissipation:
 - $~I_{CC}$ = 0.2 μA (Max.) at T_A = 85 $^{\circ}C$
- Low "ON" resistance:
 R_{ON} = 4Ω (T_A = 25°C) at V_{CC} = 3.0V
- Wide operating voltage range:
 V_{CC} (Opr) = 1.65V to 4.3V single supply
- 4.3V tolerant and 1.8V compatible threshold on digital control input at V_{CC} = 2.3V to 3.0V
- Typical bandwidth (-3dB) at 800MHz on all channels
- Latch-up performance exceeds 100mA per JESD 78, Class II
- ESD performance exceeds JESD22
 2000-V Human body model (A114-A)
- USB (2.0) high speed (480Mbps) signal switching compliant



QFN16L (2.6mm x 1.8mm)

Description

The STG3693 is a high-speed CMOS low voltage quad analog S.P.D.T. (Single Pole Dual Throw) Switch or 2:1 Multiplexer /Demultiplexer Switch fabricated in silicon gate C2MOS technology. It is designed to operate from 1.65V to 4.3V, making this device ideal for portable applications.

The nSEL inputs are provided to control the switch. The switch S1 is ON (they are connected to common Ports Dn) when the nSEL input is held high and OFF (high impedance state exists between the two ports) when SEL is held low; the switch S2 is ON (it is connected to common Port D) when the nSEL input is held low and OFF (high impedance state exists between the two ports) when nSEL is held high.

Additional key features are fast switching speed, Break Before Make Delay Time and Ultra Low Power Consumption. All inputs and outputs are equipped with protection circuits against static discharge, giving them ESD immunity and transient excess voltage.

Order codes

Part number	Package	Packaging		
STG3693QTR	QFN16L (2.6mm x 1.8mm)	Tape and reel		

Contents

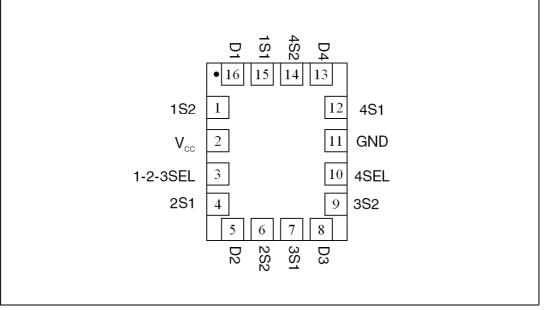
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1 Pin settings

1.1 Pin connection

Figure 1. Pin connection (top through view)



1.2 Pin description

Table 1. Pin description

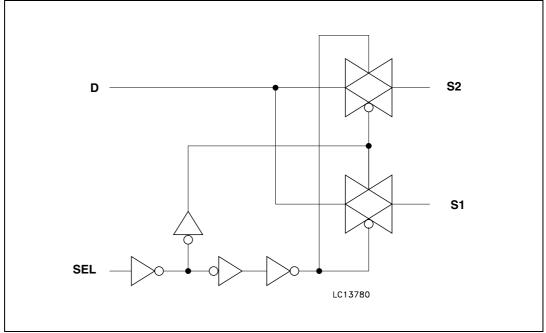
Pin N°	Symbol	Name and function
15,1, 4,6, 7,9, 12,14	1S1, 1S2, 2S1, 2S2, 3S1, 3S2, 4S1, 4S2	Independent channels
16,5,8,13	D1, D2, D3, D4	Common channels
3, 10	1-2-3SEL, 4SEL	Control
2	V _{CC}	Possitive supply voltage
11	GND	Ground (0V)

Note:

Exposed pad must be soldered to a floating plane. Do NOT connect to power or ground.



2 Device summary



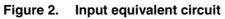


Table 2. Truth table

1-2-3SEL	4SEL	SWITCH 1	SWITCH 2	SWITCH 3	SWITCH 4
Н	Х	D1-1S1	D2-2S1	D3-3S1	Х
L	Х	D1-1S2	D2-2S2	D3-3S2	Х
Х	Н	х	Х	Х	4D-4S1
Х	L	х	Х	Х	4D-4S2



3 Maximum rating

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	-0.5 to 5.5	V
VI	DC input voltage	-0.5 to V _{CC} + 0.5	V
V _{IC}	DC control input voltage	-0.5 to 5.5	V
Vo	DC output voltage	-0.5 to V _{CC} + 0.5	V
I _{IKC}	DC input diode current on control pin (V _{SEL} <0V)	-50	mA
Ι _{ΙΚ}	DC input diode current (V _{SEL} <0V)	±50	mA
Ι _{ΟΚ}	DC output diode current	±20	mA
Ι _Ο	DC output current	±128	mA
I _{OP}	DC output current peak (pulse at 1ms, 10% duty cycle)	±300	mA
I _{CC} or I _{GND}	DC V _{CC} or ground current	±100	mA
PD	Power dissipation at $T_A = 70^{\circ}C^{(1)}$	1120	mW
T _{stg}	Storage temperature	-65 to 150	°C
ΤL	Lead temperature (10 sec)	300	°C

Table 3.	Absolute	maximum	ratings
	Absolute	maximum	raungs

1. Derate above 70°C by 18.5mW/C

3.1 Recommended operating conditions

Table 4. Recommended operating conditions

Symbol	Paramete	Value	Unit		
V _{CC}	Supply voltage ⁽¹⁾		1.65 to 4.3	V	
VI	Input voltage	0 to V _{CC}	V		
V _{IC}	Control input voltage	0 to 4.3	V		
Vo	Output voltage	0 to V _{CC}	V		
T _{op}	Operating temperature		-55 to 125	°C	
dt/dv	Input rise and fall time control	V _{CC} = 1.65V to 2.7V	0 to 20	ns/V	
al/av	input	V _{CC} = 3.0 to 4.3V	0 to 10	ns/v	

1. Truth Table guaranteed: 1.2V to 4.3V



4 Electrical characteristics

Table 5. DC Specifications

		Test conditions							
Symbol	Parameter			Тд	T _A = 25°C		-40 to	85°C	Unit
		Vcc (V)		Min	Тур	Мах	Min	Max	
		1.65 -1.95		0.65V _{CC}			$0.65V_{CC}$		
		2.3-2.5		1.2			1.2		
V_{IH}	High level input voltage	2.7-3.0		1.3			1.3		V
	input voltage	3.3-3.6		1.4			1.4		
		4.3		1.6			1.6		
		1.65-1.95				0.25			
		2.3-2.5				0.25			
V _{IL}	Low level input voltage	2.7-3.0				0.25			V
	input voltage	3.3-3.6				0.30			
		4.3				0.40			
		1.8			12.0	16.0			Ω
	Switch ON peak resistance	2.7	$V_{S} = 0V$ to V_{CC} I _S = 8mA		6.3	8.0			
R _{PEAK}		3.0			5.8	7.5			
		3.7			5.0	6.5			
		4.3	-		4.6	6.0			
D	Switch On	3.0	$V_{\rm S} = 3V I_{\rm S} = 8mA$		4.0	5.2			Ω
R _{ON}	resistance	3.0	$V_{\rm S} = 0.8 V I_{\rm S} = 8 m A$		5.0	6.5			52
		1.8							
	ON resistance	2.7							
ΔR_{ON}	match	3.0	– V _S @ R _{ON} Max _ I _S = 8mA		0.3				Ω
	between channels	3.7							-
	Charmers	4.3	_						
		1.8			6.6				
	ON	2.7			2.0				Ω
R _{FLAT}	resistance	3.0	$V_{S} = 0V$ to V_{CC} $I_{S} = 8mA$		1.7				
	flatness	3.7			1.5				
		4.3	1		1.6		Ī		1
I _{OFF}	OFF state leakage current (SN), (D)	4.3	$V_{\rm S} = 0.3 \text{ or } 4 \text{V}$			±20		±100	nA



		Test conditions		Value						
Symbol	Parameter			T,	T _A = 25°C		-40 to	85°C	Unit	
		Vcc (V)		Min	Тур	Max	Min	Max		
I _{IN}	Input leakage current	0 to 4.3	V _{SEL} = 0 to 4.3V			±0.1		±1	μA	
I _{CC}	Quiescent supply current	1.65 to 4.3	V _{SEL} = V _{CC} or GND			±0.1		±1.0	μA	
ICCLV	Quiescent supply current low voltage driving	Quiescent		V _{1-2-3SEL,} V _{4-SEL} = 1.65V		±37	±50		±100	
		current low 4.3	V _{1-2-3SEL,} V _{4-SEL} = 1.80V		±33	±40		±50	μA	
			V _{1-2-3SEL,} V _{4-SEL} = 2.60V		±11	±20		±30		

Table 5. DC Specifications (continued)

		Test co	onditions	Value					
Symbol	Parameter				T _A = 25°0		-40 to	o 85°C	Unit
		Vcc (V)		Min	Тур	Max	Min	Max	
		1.65-1.95			0.30				
t t	Propagation	2.3-2.7			0.30				ns
t _{PLH} , t _{PHL}	delay	3.0-3.3			0.25				115
		3.6-4.3			0.25				
		1.65-1.95	V _S = 0.8V		31				
tau	TURN-ON	2.3-2.7			20	26		34	
t _{ON}	time	3.0-3.3	V _S = 1.5V		20	20		26	_ ns
		3.6-4.3			20	15		20	
	1.65-1.95 V _S = 0.8 TURN-OFF 2.3-2.7	1.65-1.95	V _S = 0.8		5				
t				4	6		8	ns	
t _{OFF}	time	3.0-3.3	V _S = 1.5V		4	6		8	
		3.6-4.3			3	5		6	
		1.65-1.95		1	7				
t _D	Break before make	2.3-2.7	C _L = 35pF R _L = 50Ω	1	5				ns
۲D	time delay	3.0-3.3	$V_{\rm S} = 1.5V$	1	4				
		3.6-4.3		1	3				
		1.65			2.8				pC
Q	Charge	2.3	$C_{L} = 100 pF$		3.5				
Q	injection	3.0	V _{GEN} = 0V R _{GEN} = 0Ω		3.8				
		4.3			5.0				



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		٦	Test Conditions	Value					
Symbol	Parameter			T _A = 28		С	-40 to 85°C		Unit
		Vcc (V)		Min	Тур	Max	Min	Max	
		1.65 - 4.3	$V_S = 1V_{RMS,} f = 1MHz$ Signal = 0 dBm		-79				dD
OIRR	Off Isolation ⁽¹⁾	1.05 - 4.3	$V_S = 1V_{RMS,} f = 10MHz$ Signal = 0 dBm		-60				dB
Xtalk	Crosstalk	1.65 4.2	V _S = 1V _{RMS,} f = 1MHz Signal = 0 dBm		-78				dB
λιαικ	Crossiaik	1.65 - 4.3	$V_S = 1V_{RMS,} f = 10MHz$ Signal = 0 dBm		-61				uв
THD	Total harmonic distortion	3.7	f = 20Hz to 20kHz $R_L = 32\Omega, C_L = 50\Omega$ $V_{IN} = 2.8V_{P-P}$ $V_{DC} = V_{CC}/2$		0.01	0.02			%
PSRR	Power supply rejection ratio	3.7	f = 217Hz, $R_L = 32\Omega, C_L = 50\Omega$ $V_{ripple} = 150mV$ $V_{DC} = V_{CC}/2$		-60				dB
BW	-3dB Bandwidth	3.0 - 4.3	R _L = 50Ω Signal = 0dBm		800				MHz
D _G	Differential gain	3.0 - 4.3	RL = 150Ω		0.64				%
DP	Differential phase	3.0 - 4.3	RL = 150Ω		0.1				deg
C _{IN}	Control pin input capacitance		$V_{CC} = 0V$		6.2				
C _{ON}	Sn Port capacitance when switch is enabled	3.3	f = 1MHz		10				pF
C _{OFF}	Sn port capacitance when switch is disabled	3.3	f = 1MHz		21				-

Table 7. Analog switch characteristics (C $_L$ = 5pF, R $_L$ = 50Ω, T $_A$ = 25°C)

1. Off Isolation = 20Log10 (V_D/V_S), V_D = output. V_S = input to off switch.

Symbol	Parameter	Test conditions		Value					
		V _{CC} (V)		T _A = 25°C		-40 to 85°C		Unit	
				Min	Тур	Max	Min	Max	
t _{SK(0)}	Channel-to-channel skew	3.0 to 3.6	C _L =10pF		26				ps
t _{SK(P)}	Skew of opposite transition of the same output	3.0 to 3.6	C _L =10pF		60				ps
ТJ	Total jitter	3.0 to 3.6	$R_L = 50\Omega$, $C_L = 10$ pF, $t_R = t_F = 750$ ps at 480 Mbps		130				ps

5 Test circuits

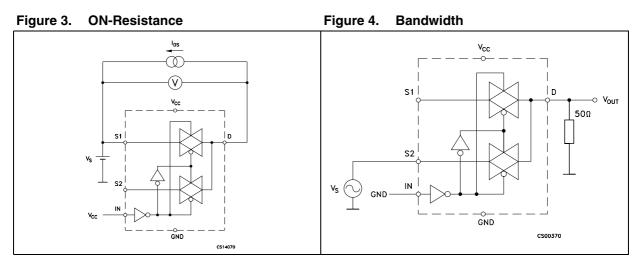
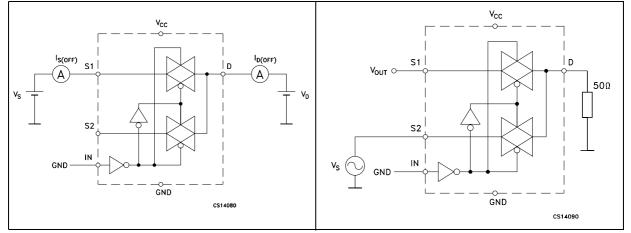
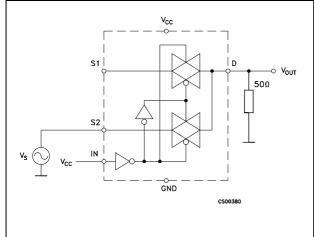


Figure 5. OFF Leakage

Figure 6. Channel to channel crosstalk

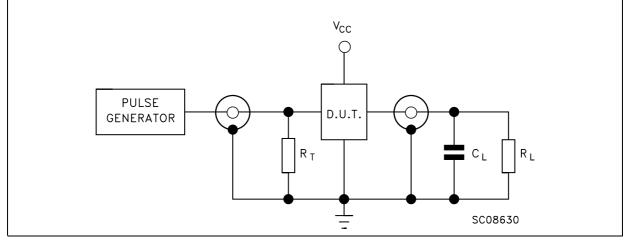






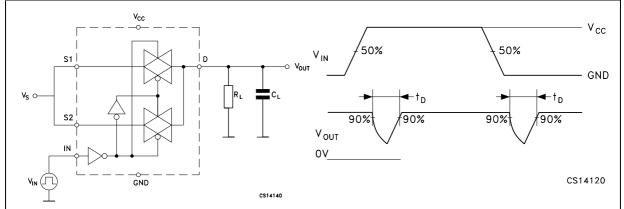
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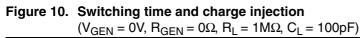
Figure 8. Test circuit

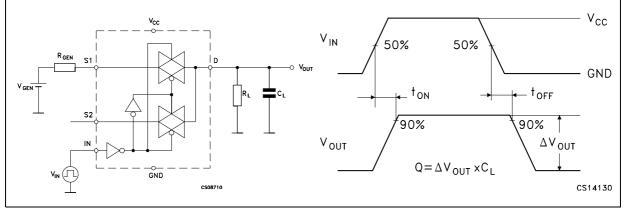


- *Note:* 1 $C_L = 5/35$ pF or equivalent: (includes jig capacitance)
 - 2 $R_L = 50\Omega$ or equivalent
 - 3 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

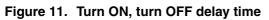


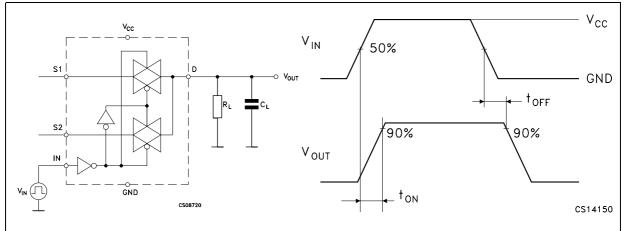






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6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com



Dim.	mm.					
Dini.	Min	Тур	Мах			
A	0.45	0.50	0.55			
A1	0	0.02	0.05			
A3		0.127				
b	0.15	0.20	0.25			
D	2.50	2.60	2.70			
D2	1.40	1.50	1.60			
E	1.70	1.80	1.90			
E2	0.60	0.70	0.80			
e		0.40				
L	0.25	0.30	0.35			

Table 9. QFN16L (2.6x1.8mm) mechanical data

Note:

1 VFQFPN - Standard for thermally enhanced vey fine pitch quad flat package no leads.

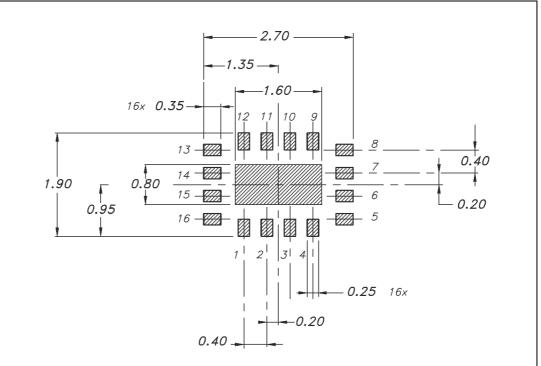
2 The leads size is comprehensive of the thickness of the leads finishing material.

3 Dimensions do not include mold protusion.

4 Package outline exclusive of metal burrs dimensions.

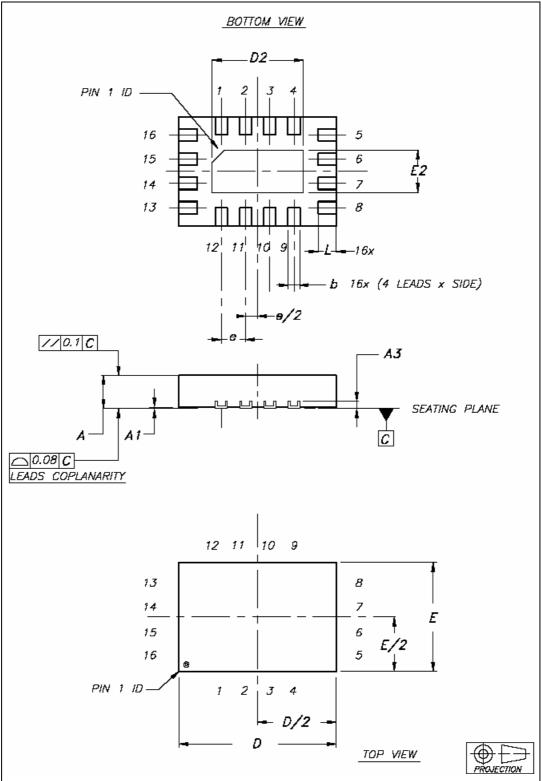
5 Shipping media tape and reel units: 3000

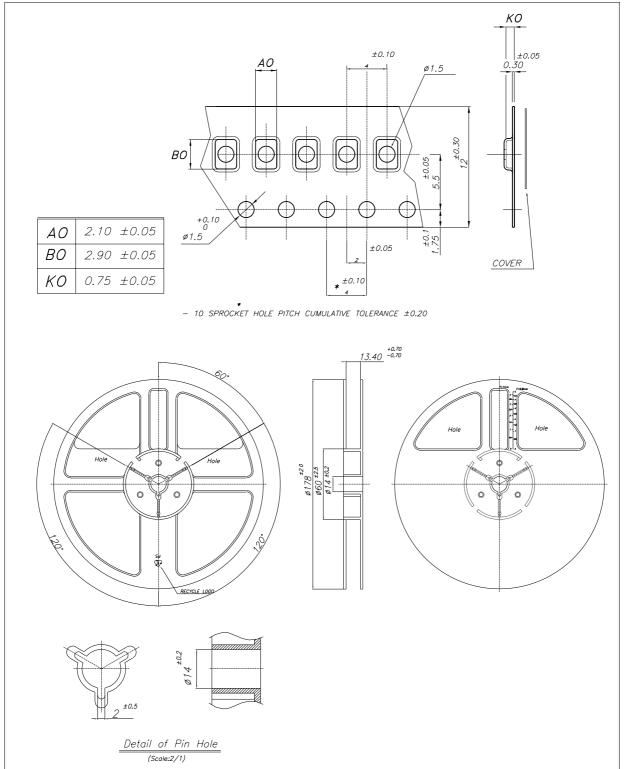
Figure 12. Foot print recommendation















7 Revision history

Table 10. Revision history

Date	Revision	Changes
3-Jan-2006	1	First release



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